Unit in mm

## TOSHIBA VARIABLE CAPACITANCE DIODE SILICON EPITAXIAL PLANAR TYPE

# 1 S V 2 4 5

**UHF SHF TUNING** 

High Capacitance Ratio : C2V/C25V=5.7 (Typ.)

Low Series Resistance :  $rs = 1.2\Omega$  (Typ.)

Excellent C-V Characteristics, and Small Tracking Error.

#### MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage	$v_{R}$	30	V
Peak Reverse Voltage	$ m V_{RM}$	$(R_L = 10 k\Omega)$	V
Junction Temperature	$T_{j}$	125	$^{\circ}\mathrm{C}$
Storage Temperature Range	${ m T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$

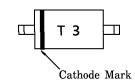
# MARK $1.25^{+0.2}_{-0.1}$ CATHODE 7+0:2 $0 \pm 0.05$ 0. 3+0:1 0. $15^{+0.1}_{-0.00}$ **JEDEC EIAJ** TOSHIBA 1-1E1A

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Reverse Voltage	$v_{ m R}$	$I_R = 1 \mu A$	30			V
Reverse Current	$I_{ m R}$	$V_R = 28V$	_	_	10	nA
Capacitance	C2V	$V_R=2V$ , $f=1MHz$	3.31	_	4.55	рF
Capacitance	C25V	$V_R$ =25V, f=1MHz	0.61	_	0.77	рF
Capacitance Ratio	C2V / C25V	_	5.0	5.7	6.5	_
Series Resistance	$r_{\mathrm{S}}$	$V_R=1V, f=470MHz$	_	1.2	2.0	Ω

Note1: Unites are compounded in one package and are matched to 6.0%.

$$\frac{\text{C (Max.)} - \text{C (Min.)}}{\text{C (Min.)}} \leq 0.06 \text{ (VR} = 2 \sim 25 \text{V)}$$



Marking

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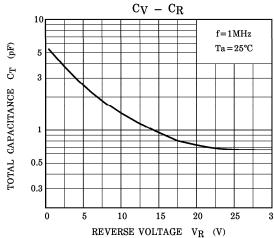
1.6

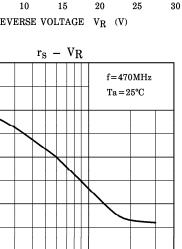
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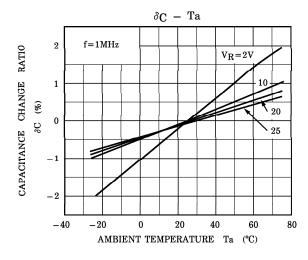
0.8

0.4

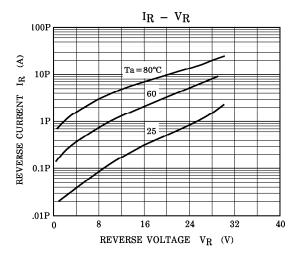
SERIES RESISTANCE r<sub>s</sub> (Ω)

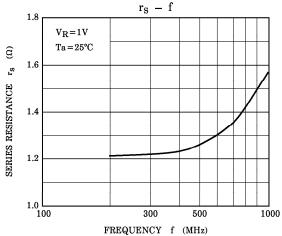






REVERSE VOLTAGE  $V_R$  (V)





NOTE : 
$$\delta_{\text{C}}$$
 (%)=  $\frac{\text{C (Ta)} - \text{C (25)}}{\text{C (25)}} \times 100$